

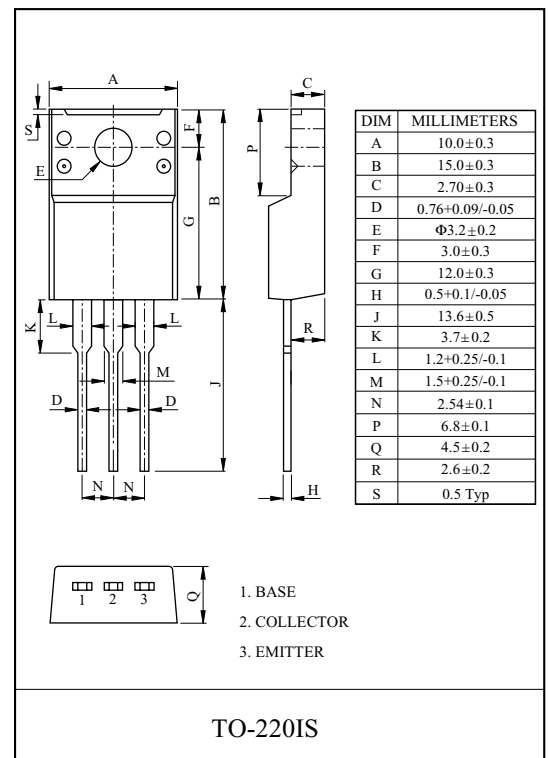
GENERAL PURPOSE APPLICATION.

FEATURES

- Low Collector Saturation Voltage
: $V_{CE(sat)} = -1.0V$ (Max.) at $I_C = -2A$, $I_B = -0.2A$.
- Collector Power Dissipation
: $P_C = 25W$ ($T_c = 25^\circ C$)
- Complementary to KTD2058.

MAXIMUM RATING ($T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	-60	V
Collector-Emitter Voltage	V_{CEO}	-60	V
Emitter-Base Voltage	V_{EBO}	-7	V
Collector Current	I_C	-3	A
Base Current	I_B	-0.5	A
Collector Power Dissipation	P_C	2	W
		25	
Junction Temperature	T_j	150	$^\circ C$
Storage Temperature Range	T_{stg}	-55 ~ 150	$^\circ C$

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = -60V$, $I_E = 0$	-	-	-100	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = -7V$, $I_C = 0$	-	-	-100	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -50mA$, $I_B = 0$	-60	-	-	V
DC Current Gain	$h_{FE(1)}$ (Note)	$V_{CE} = -5V$, $I_C = -0.5A$	60	-	200	
	$h_{FE(2)}$	$V_{CE} = -5V$, $I_C = -3A$	20	-	-	
Collector Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -2A$, $I_B = -0.2A$	-	-0.25	-1.0	V
Base-Emitter Voltage	V_{BE}	$V_{CE} = -5V$, $I_C = -0.5A$	-	-0.7	-1.0	V
Transition Frequency	f_T	$V_{CE} = -5V$, $I_C = -0.5A$	-	9	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = -10V$, $I_E = 0$, $f = 1MHz$	-	150	-	pF
Switching Time	Turn-on Time	t_{on}	-	0.4	-	μs
	Storage Time	t_{stg}	-	1.7	-	
	Fall Time	t_f	-	0.5	-	

Note : $h_{FE(1)}$ Classification O:60 ~ 120, Y:100 ~ 200

